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## METHOD OF SELF-ANNEALING CONDUCTIVE LINES THAT SEPARATES GRAIN SIZE EFFECTS FROM ALLOY MOBILITY

## ABSTRACT OF THE DISCLOSURE

A method of forming a conductive structure such as a copper conductive structure, line, or via is optimized for large grain growth and distribution of alloy elements. The alloy elements can reduce electromigration problems associated with the conductive structure. The conductive structure is self-annealed or first annealed in a low temperature process over a longer period of time. Another anneal is utilized to distribute alloy elements.

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